

این دیتاشیت توسط توکل الکترونیک تهیه و ارائه شده است.
جهت مشاهده قیمت، موجودی و ثبت سفارش این قطعه به وبسایت توکل الکترونیک مراجعه فرمایید.



مشاهده قیمت و خرید

برای خرید و مشاهده سایر محصولات کلیک کنید



2N7000
2N7002

N-channel 60 V, 1.8 Ω , 0.35 A, SOT23-3L, TO-92
STripFET™ Power MOSFET

Features

Type	V _{DSS}	R _{DS(on)} max	I _D
2N7000	60 V	< 5 Ω (@10V)	0.35 A
2N7002	60 V	< 5 Ω (@10V)	0.20 A

- Low Q_g
- Low threshold drive

Application

- Switching applications

Description

This Power MOSFET is the second generation of STMicroelectronics unique “single feature size” strip-based process. The resulting transistor shows extremely high packing density for low on-resistance, rugged avalanche characteristics and less critical alignment steps therefore a remarkable manufacturing reproducibility.

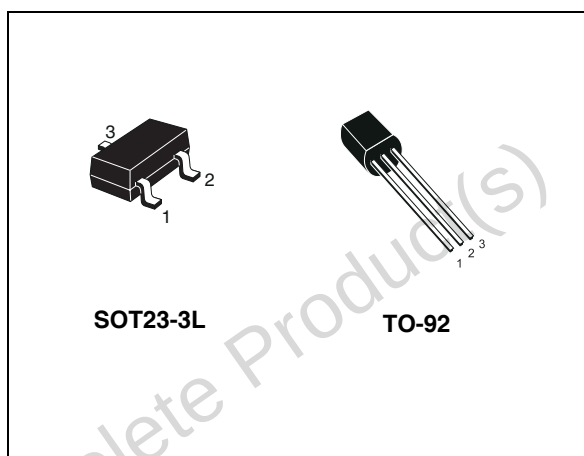


Figure 1. Internal schematic diagram

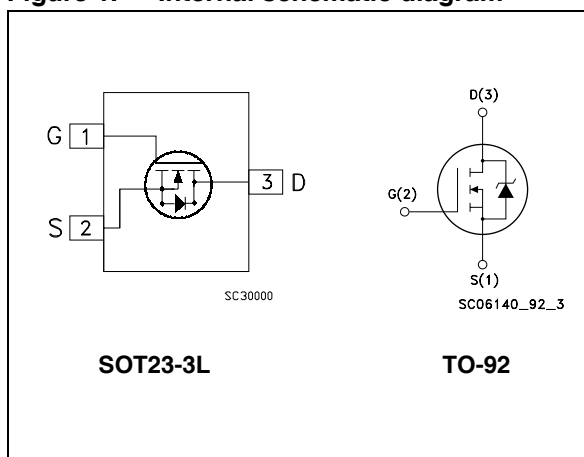


Table 1. Device summary

Order codes	Marking	Package	Packaging
2N7000	2N7000G	TO-92	Bulk
2N7002	ST2N	SOT23-3L	Tape and reel

Contents

1 **Electrical ratings** 3

2 **Electrical characteristics** 4

 2.1 Electrical characteristics (curves) 6

3 **Test circuits** 9

4 **Package mechanical data** 10

5 **Revision history** 13

Obsolete Product(s) - Obsolete Product(s)



1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value		Unit
		TO-92	SOT23-3L	
V_{DS}	Drain-source voltage ($V_{GS} = 0$)	60		V
V_{DGR}	Drain-gate voltage ($R_{GS} = 20\text{ k}\Omega$)	60		V
V_{GS}	Gate- source voltage	± 18		V
I_D	Drain current (continuous) at $T_C = 25\text{ }^\circ\text{C}$	0.35	0.20	A
$I_{DM}^{(1)}$	Drain current (pulsed)	1.4	1	A
P_{TOT}	Total dissipation at $T_C = 25\text{ }^\circ\text{C}$	1	0.35	W

1. Pulse width limited by safe operating area

Table 3. Thermal data

Symbol	Parameter	Value		Unit
		TO-92	SOT23-3L	
$R_{thj-amb}$	Thermal resistance junction-ambient max	125	357.1 ⁽¹⁾	$^\circ\text{C/W}$
T_J	Operating junction temperature	- 55 to 150		$^\circ\text{C}$
T_{stg}	Storage temperature			

1. When mounted on 1inch² FR-4, 2 Oz copper board.

2 Electrical characteristics

($T_{CASE} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Table 4. On/off states

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{(BR)DSS}$	Drain-source breakdown voltage	$I_D = 250\text{ }\mu\text{A}$, $V_{GS} = 0$	60			V
I_{DSS}	Zero gate voltage drain current ($V_{GS} = 0$)	$V_{DS} = \text{max rating}$ $V_{DS} = \text{max rating}$, $T_C = 125\text{ }^{\circ}\text{C}$			1 10	μA μA
I_{GSS}	Gate-body leakage current ($V_{DS} = 0$)	$V_{GS} = \pm 18\text{ V}$			± 100	nA
$V_{GS(th)}$	Gate threshold voltage	$V_{DS} = V_{GS}$, $I_D = 250\text{ }\mu\text{A}$	1	2.1	3	V
$R_{DS(on)}$	Static drain-source on resistance	$V_{GS} = 10\text{ V}$, $I_D = 0.5\text{ A}$ $V_{GS} = 4.5\text{ V}$, $I_D = 0.5\text{ A}$		1.8 2	5 5.3	Ω Ω

Table 5. Dynamic

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$g_{fs}^{(1)}$	Forward transconductance	$V_{DS} = 10\text{ V}$, $I_D = 0.5\text{ A}$		0.6		S
C_{iss} C_{oss} C_{rss}	Input capacitance Output capacitance Reverse transfer capacitance	$V_{DS} = 25\text{ V}$, $f = 1\text{ MHz}$, $V_{GS} = 0$		43 20 6		pF pF pF
$t_{d(on)}$ t_r $t_{d(off)}$ t_f	Turn-on delay time Rise time Turn-off delay time Fall time	$V_{DD} = 30\text{ V}$, $I_D = 0.5\text{ A}$ $R_G = 4.7\text{ }\Omega$, $V_{GS} = 4.5\text{ V}$ (see Figure 16)		5 15 7 8		ns ns ns ns
Q_g Q_{gs} Q_{gd}	Total gate charge Gate-source charge Gate-drain charge	$V_{DD} = 30\text{ V}$, $I_D = 1\text{ A}$, $V_{GS} = 5\text{ V}$ (see Figure 17)		1.4 0.8 0.5	2	nC nC nC

1. Pulsed: Pulse duration = 300 μs , duty cycle 1.5%.

Table 6. Source drain diode

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{SD} $I_{SDM}^{(1)}$	Source-drain current Source-drain current (pulsed)				0.35 1.40	A A
$V_{SD}^{(2)}$	Forward on voltage	$I_{SD} = 1\text{ A}$, $V_{GS} = 0$			1.2	V
t_{rr} Q_{rr} I_{RRM}	Reverse recovery time Reverse recovery charge Reverse recovery current	$I_{SD} = 1\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$, $V_{DD} = 20\text{ V}$, $T_j = 150\text{ }^\circ\text{C}$ (see Figure 18)		32 25 1.6		ns nC A

1. Pulse width limited by safe operating area.

2. Pulsed: Pulse duration = 300 μs , duty cycle 1.5%

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area for TO-92

Figure 3. Thermal impedance for TO-92

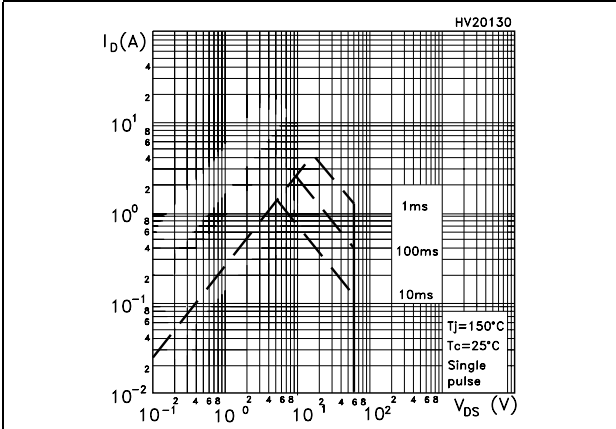
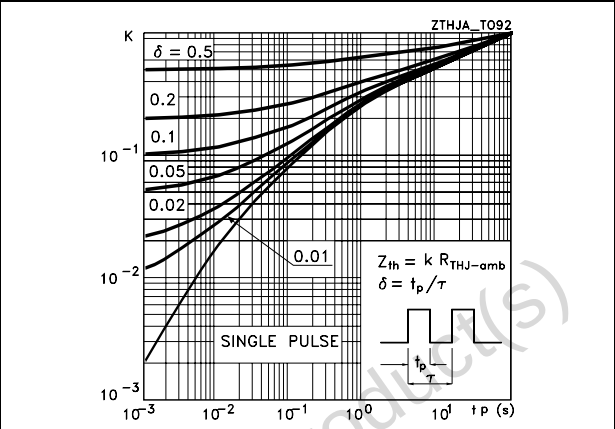


Figure 4. Safe operating area for SOT23-3L

Figure 5. Thermal impedance for SOT23-3L

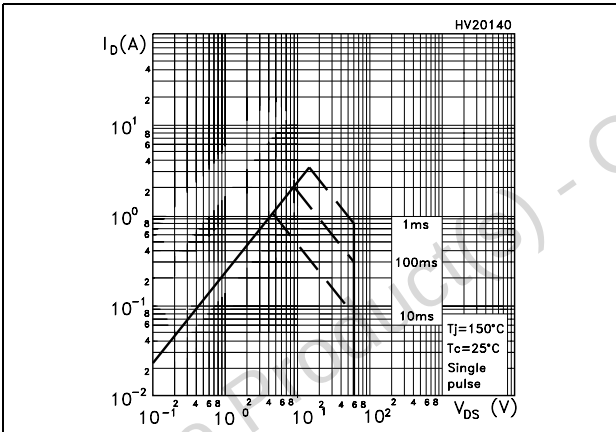
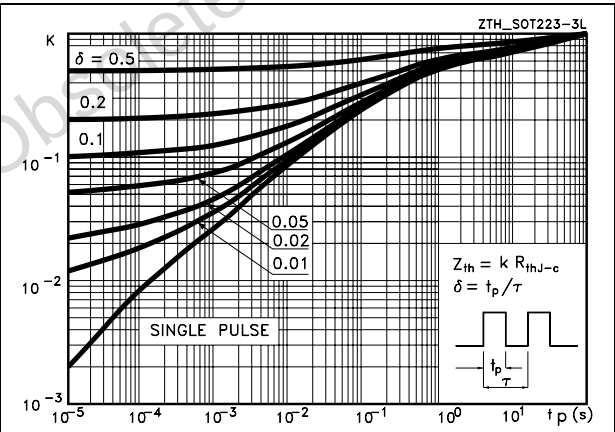


Figure 6. Output characteristics

Figure 7. Transfer characteristics

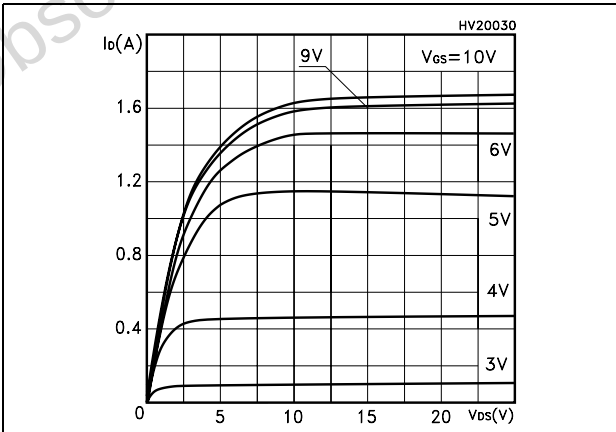
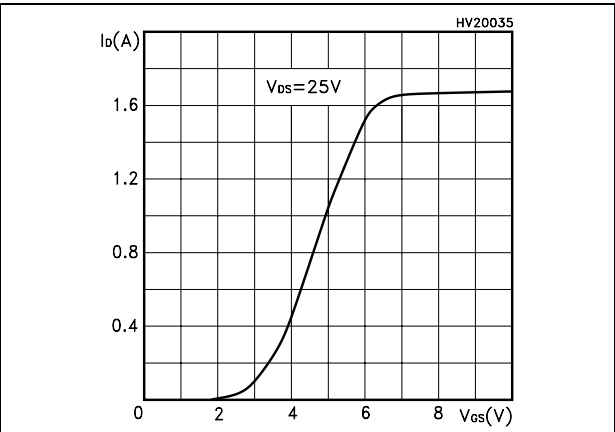


Figure 8. Transconductance

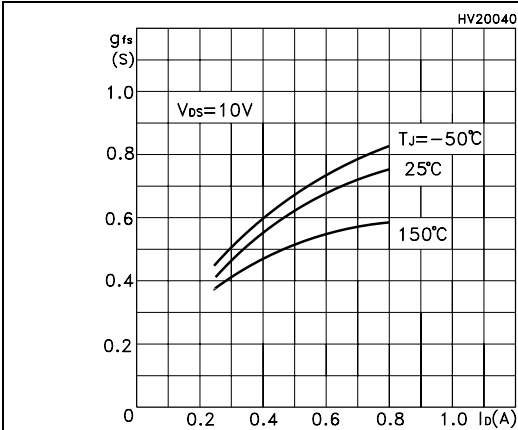


Figure 9. Static drain-source on resistance

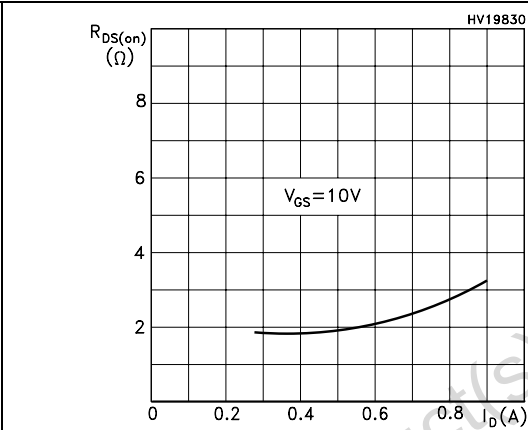


Figure 10. Gate charge vs gate-source voltage

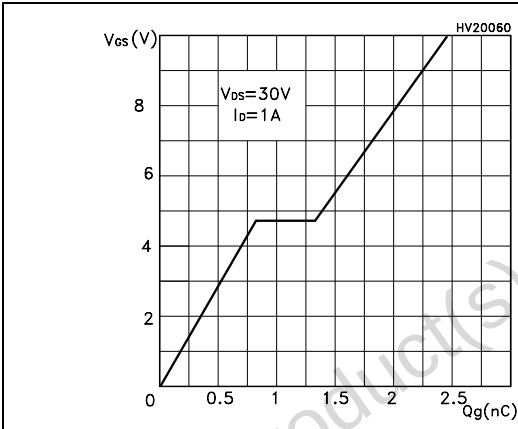


Figure 11. Capacitance variations

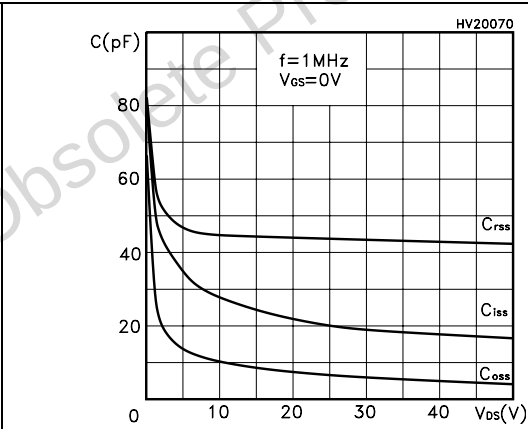


Figure 12. Normalized gate threshold voltage vs temperature

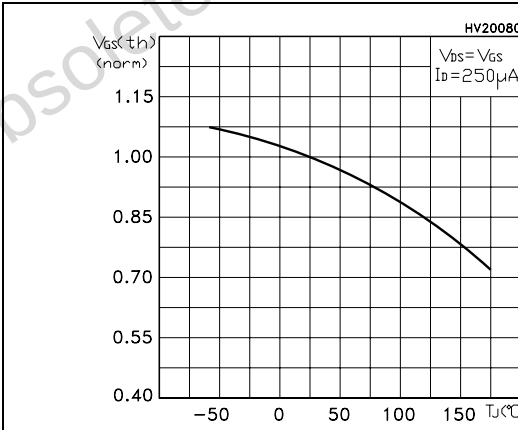


Figure 13. Normalized on resistance vs temperature

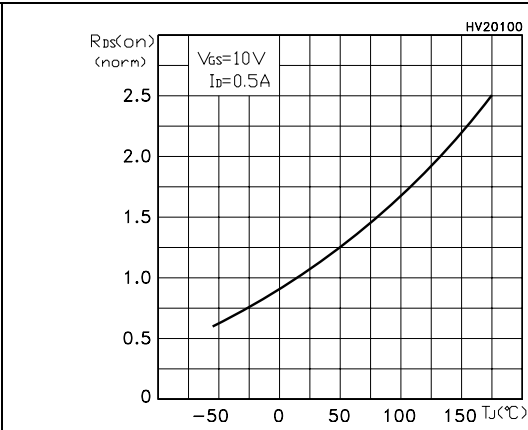


Figure 14. Source-drain diode forward characteristics

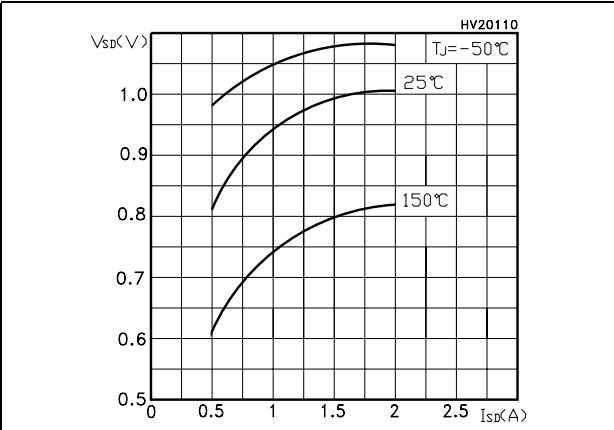
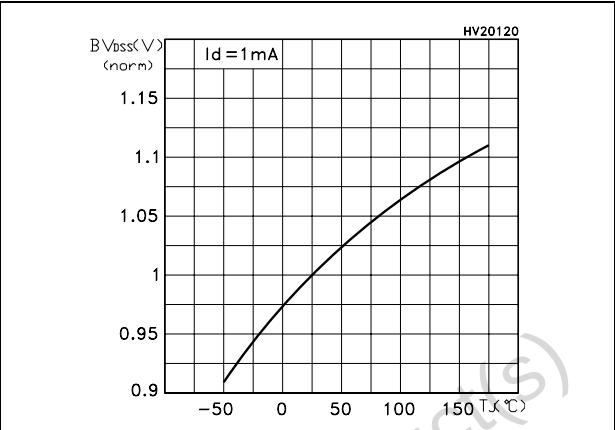


Figure 15. Normalized B_{VDSS} vs temperature



3 Test circuits

Figure 16. Switching times test circuit for resistive load

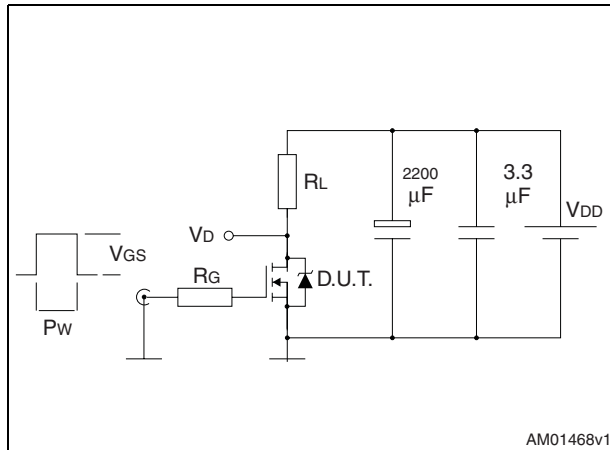


Figure 17. Gate charge test circuit

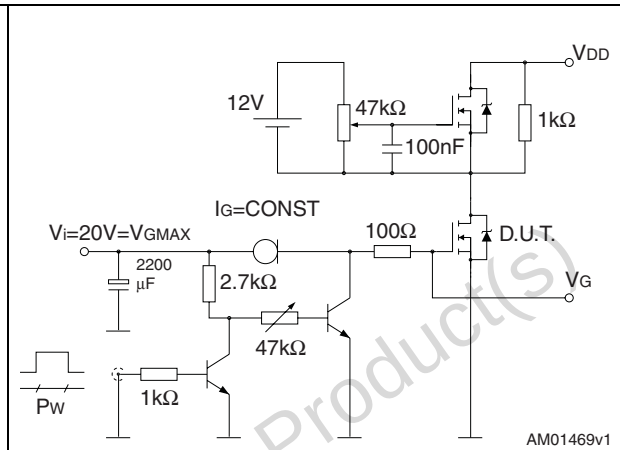


Figure 18. Test circuit for inductive load switching and diode recovery times

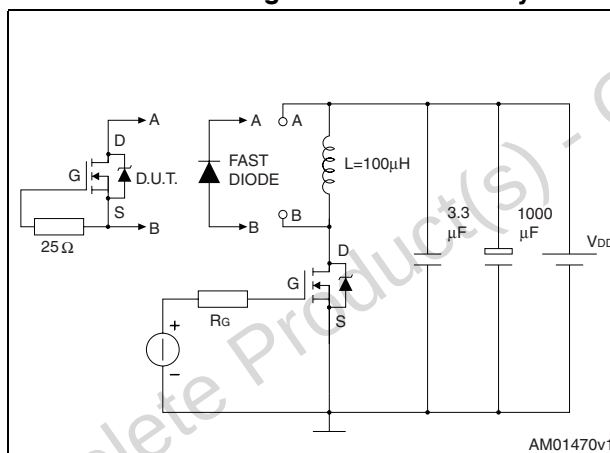


Figure 19. Unclamped Inductive load test circuit

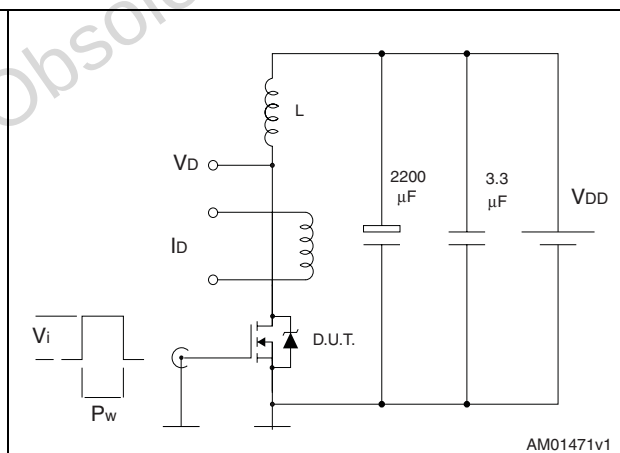


Figure 20. Unclamped inductive waveform

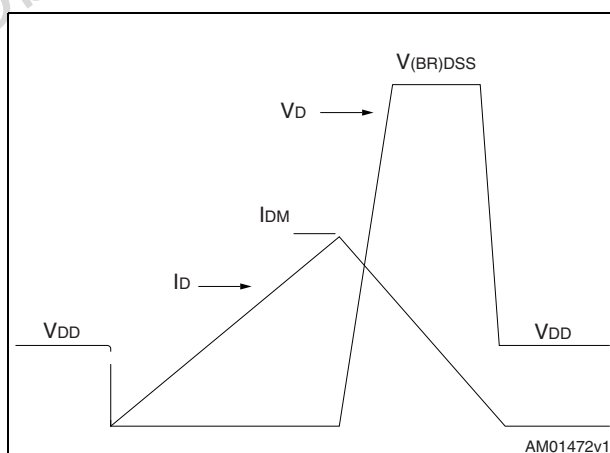
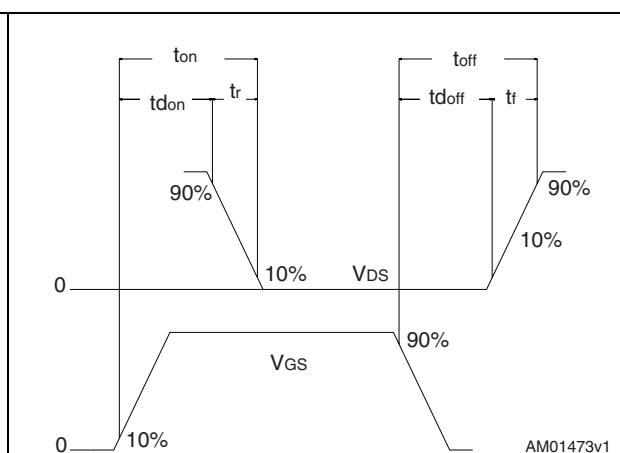


Figure 21. Switching time waveform



4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

Obsolete Product(s) - Obsolete Product(s)

Table 7. TO-92 mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.32		4.95
b	0.36		0.51
D	4.45		4.95
E	3.30		3.94
e	2.41		2.67
e1	1.14		1.40
L	12.70		15.49
R	2.16		2.41
S1	0.92		1.52
W	0.41		0.56
V		5°	

Figure 22. TO-92 drawing

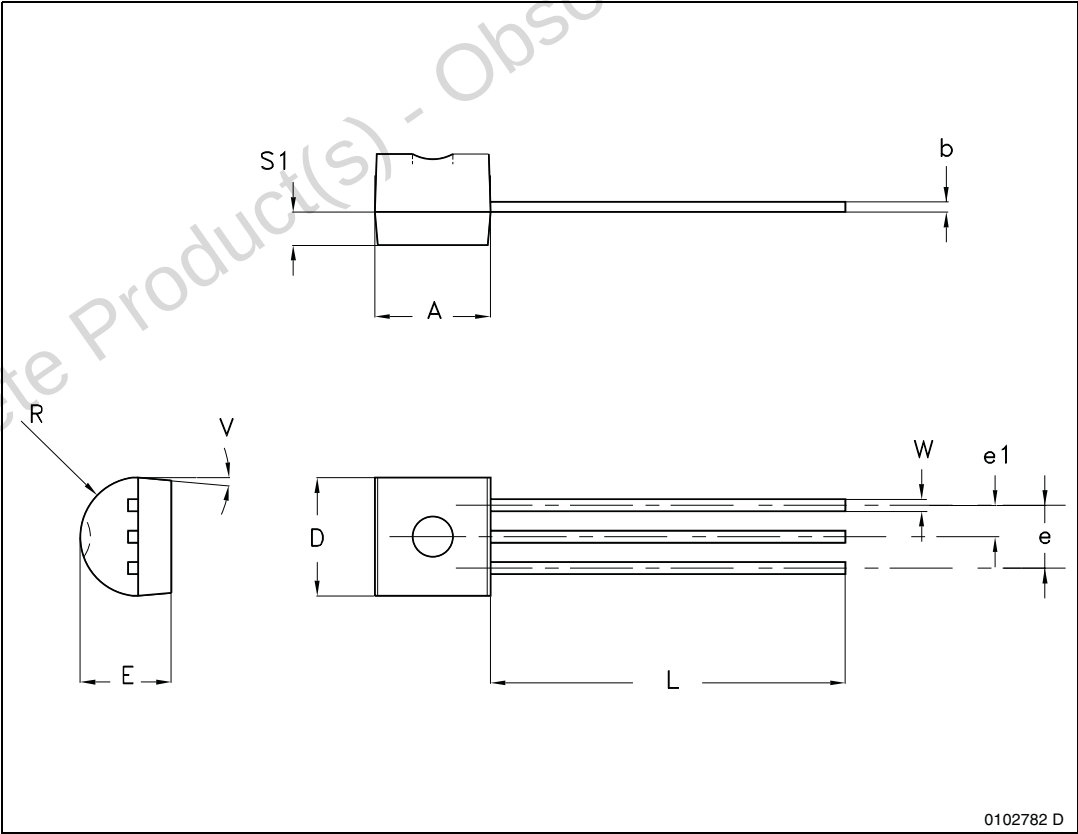
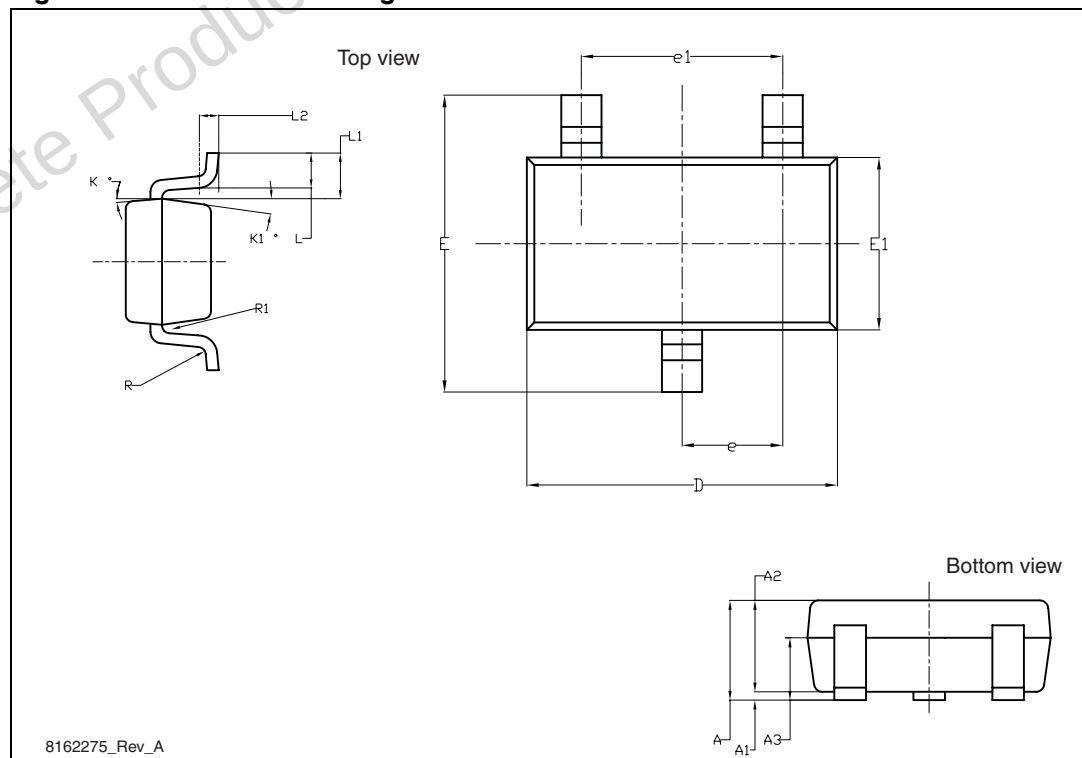


Table 8. SOT23-3L mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A			1.25
A1	0		0.15
A2	1.00		1.20
A3	0.60		0.70
D	2.826		3.026
E	2.60		3.00
E1	1.526		1.726
e		0.95	
e1		1.90	
L	0.35		0.60
L1		0.59	
L2		0.25	
R	0.05		
R1	0.05		0.20
K	3°		7°
K1	6°		10°

Figure 23. SOT23-3L drawing



5 Revision history

Table 9. Document revision history

Date	Revision	Changes
09-Oct-2004	1	First document
22-Jun-2004	2	Complete document
06-Apr-2005	3	New typ and max value inserted for Vgs(th)
19-Apr-2005	4	The document has been reformatted
26-Apr-2005	5	New Pin configuration for TO-92
28-Apr-2005	6	Pin configuration change again
19-Jun-2006	7	New template, no content change
03-Sep-2007	8	Corrected marking on first page
04-Nov-2008	9	<ul style="list-style-type: none"> – Updated Table 7: TO-92 mechanical data and Figure 22: TO-92 drawing. – Updated Table 8: SOT23-3L mechanical data and Figure 23: SOT23-3L drawing.

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